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Inclosure Material:

Plastic

Overall Length:

0.405 inches

Terminal Length:

0.135 inches

Overall Height:

0.250 inches

Overall Width:

0.245 inches

Lens Transparency:

Translucent all light emitting diode

Function For Which Designed:

Visible light emitting

End Application:

5895-01-163-1168

Component Name And Quantity:

4 light emitting diode

Mounting Method:

Terminal

Semiconductor Material:

Gallium arsenide phosphide all light emitting diode

Voltage Rating In Volts Per Characteristic:

5.0 forward voltage, dc all light emitting diode

Current Rating Per Characteristic:

40.00 milliamperes source cutoff current preset all light emitting diode

Color Tone Produced Per Source:

Red lens all light emitting diode

Luminous Intensity:

3.0 millicandela all light emitting diode

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius ambient air

Special Features:

All light emitting diode junction pattern arrangement: pn

Terminal Type And Quantity:

8 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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